SPN4920W N-Channel Enhancement Mode MOSFET

DESCRIPTION

The SPN4920W is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application, notebook computer power management and other battery powered circuits where high-side switching.

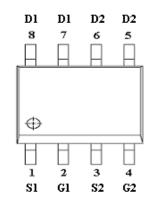
FEATURES

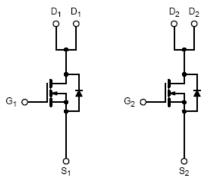
- 30V/6.8A, RDS(ON)= $35m\Omega$ @VGS=10V
- 30V/5.6A,RDS(ON)= $46m\Omega$ @VGS=4.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOP-8 package design

APPLICATIONS

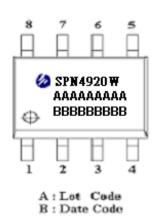
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

PIN CONFIGURATION(SOP-8)





PART MARKING



IN DESCRIPTION						
Pin	Symbol	Description				
1	S1	Source 1				
2	G1	Gate 1				
3	S2	Source 2				
4	G2	Gate 2				
5	D2	Drain 2				
6	D2	Drain 2				
7	D1	Drain 1				
8	D1	Drain 1				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN4920WS8RGB	SOP-8	SPN4920W

[※] SPN4920WS8RGB: 13" Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

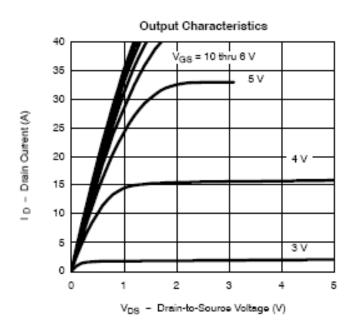
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Proin Compat/Ty-1509C)	Ta=25°C	In	7.2	Δ.	
Continuous Drain Current(TJ=150°C)	Ta=70°C	- Id	5.8	A	
Pulsed Drain Current	IDМ	30	A		
Continuous Source Current(Diode Conduction)		Is	2.3	A	
D	Ta=25°C	D-	2.5	***	
Power Dissipation	Ta=70°C	PD	1.6	W	
Operating Junction Temperature		Тл	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	80	°C/W	

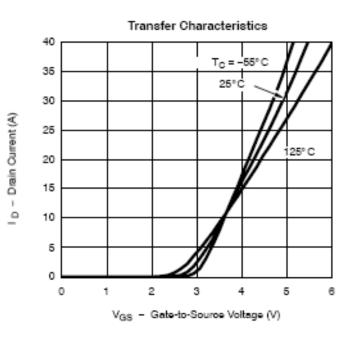
ELECTRICAL CHARACTERISTICS

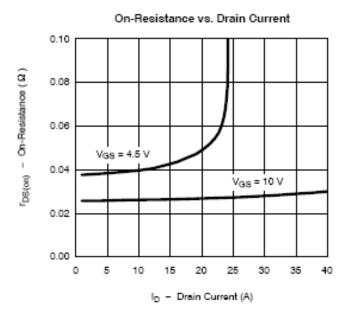
(Ta=25°C Unless otherwise noted)

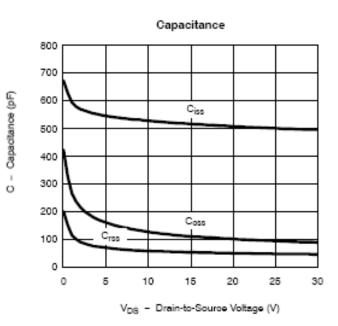
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static		1	L			
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.6		1.8	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA
Zero Gate Voltage Drain Current	IDSS	Vds=24V,Vgs=0V			1	uA
		Vds=24V,Vgs=0V Tj=55°C			5	
On-State Drain Current	ID(on)	Vds≥5V,Vgs =10V	25			A
Drain-Source On-Resistance	RDS(on)	V _{GS} = 10V,I _D =6.8A V _{GS} =4.5V,I _D =5.6A		0.030 0.037	0.035 0.046	Ω
Forward Transconductance	gfs	VDS=15V,ID=6.2A		13		S
Diode Forward Voltage	Vsd	Is=2.3A,VGS =0V		0.8	1.2	V
Dynamic			•			
Total Gate Charge	Qg	VDS=15V,VGS=10V -ID= 2A		16	24	nC
Gate-Source Charge	Qgs			3		
Gate-Drain Charge	Qgd	ID- ZA		2.5		
Input Capacitance	Ciss	VDS=15VGS=0V -f=1MHz		450		pF
Output Capacitance	Coss			240		
Reverse Transfer Capacitance	Crss			38		
Turn-On Time	td(on)			15	20	nS
	tr	VDD=15V,RL=15Ω		6	12	
Turn-Off Time	td(off)	$I_D=1.0A,V_{GEN}=10V$ $R_G=6\Omega$		10	20	
	tf			40	80	

TYPICAL CHARACTERISTICS

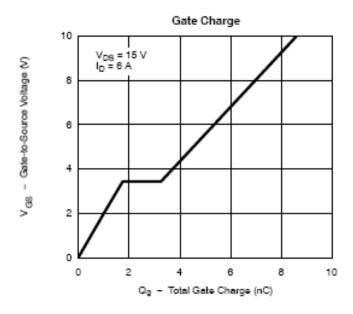


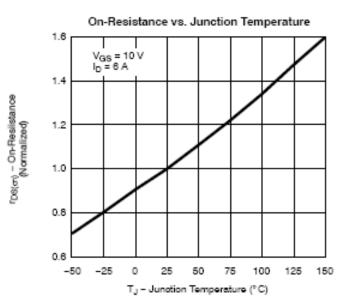


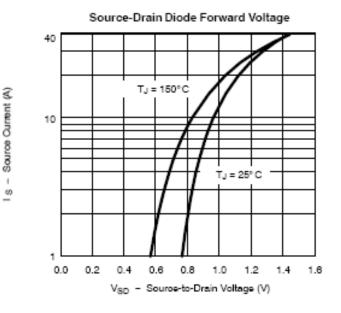


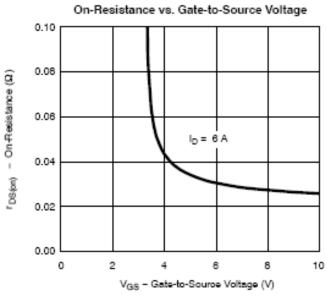


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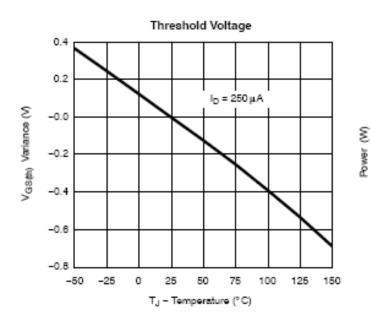


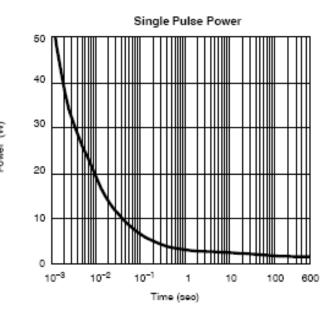




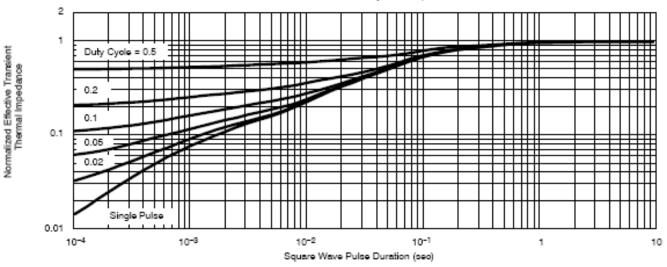


TYPICAL CHARACTERISTICS









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